

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74VHC373F, TC74VHC373FK

#### Octal D-Type Latch with 3-State Output

The TC74VHC373 is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate  $C^2$ MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

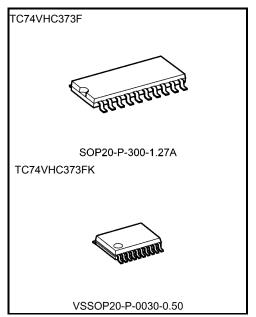
This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (  $\overline{OE}$  ).

When the  $\overline{\rm OE}$  input is high, the eight outputs are in a high impedance state

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

#### **Features**

- High speed: tpd = 5.0 ns (typ.) at VCC = 5 V
- Low power dissipation: ICC = 4 μA (max) at Ta = 25°C
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: tpLH ~ tpHL
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS373



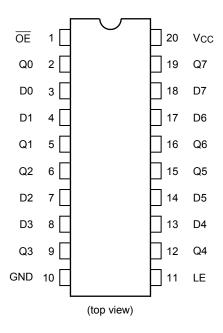
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

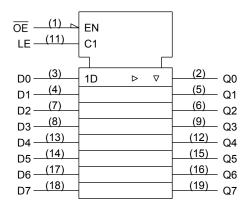
Start of commercial production 1991-05



#### **Pin Assignment**



## **IEC Logic Symbol**



#### **Truth Table**

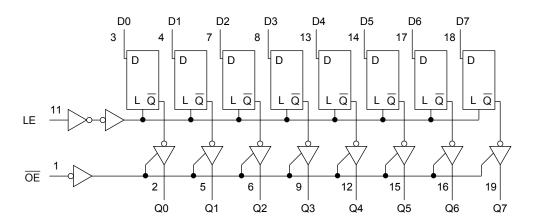
|    | Inputs |   | Output |
|----|--------|---|--------|
| ŌĒ | LE     | D | Output |
| Н  | Х      | Х | Z      |
| L  | L      | Х | Qn     |
| L  | Н      | L | L      |
| L  | Н      | Н | Н      |

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

### **System Diagram**





#### **Absolute Maximum Ratings (Note)**

| Characteristics       | Symbol           | Rating                        | Unit |
|-----------------------|------------------|-------------------------------|------|
| Supply voltage range  | Vcc              | −0.5 to 7.0                   | V    |
| DC input voltage      | VIN              | −0.5 to 7.0                   | V    |
| DC output voltage     | Vout             | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current   | lıĸ              | -20                           | mA   |
| Output diode current  | Іок              | ±20                           | mA   |
| DC output current     | lout             | ±25                           | mA   |
| DC Vcc/ground current | Icc              | ±75                           | mA   |
| Power dissipation     | PD               | 180                           | mW   |
| Storage temperature   | T <sub>stg</sub> | −65 to 150                    | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### **Operating Ranges (Note)**

| Characteristics          | Symbol          | Rating  | Unit |
|--------------------------|-----------------|---|------|
| Supply voltage           | Vcc             | 2.0 to 5.5  | V    |
| Input voltage            | V <sub>IN</sub> | 0 to 5.5  | V    |
| Output voltage           | Vout            | 0 to Vcc  | V    |
| Operating temperature    | Topr            | −40 to 85   | °C   |
| Input rise and fall time | dt/dv           | 0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)<br>0 to 20 (V <sub>CC</sub> = 5 ± 0.5 V) | ns/V |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



#### **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics                      | Symbol          | Test Condition  |                          | Ta = 25°C           |                       |      | Ta =<br>-40 to 85°C   |                       | Unit                  |    |  |
|--------------------------------------|-----------------|---|--------------------------|---------------------|-----------------------|------|-----------------------|-----------------------|-----------------------|----|--|
| Silaractoriotics                     | Cymbol          |   |                          | V <sub>CC</sub> (V) | Min                   | Тур. | Max                   | Min                   | Max                   |    |  |
| High-level input                     |                 |   |                          | 2.0                 | 1.50                  | _    | _                     | 1.50                  | _                     |    |  |
| voltage                              | VIH             | -   | _                        | 3.0 to 5.5          | V <sub>CC</sub> × 0.7 | ı    | _                     | V <sub>CC</sub> × 0.7 | _                     | V  |  |
| Low-level input                      |                 |   |                          | 2.0                 | _                     | -    | 0.50                  | _                     | 0.50                  |    |  |
| voltage                              | VIL             | -   | _                        | 3.0 to 5.5          | _                     | _    | V <sub>CC</sub> × 0.3 | _                     | V <sub>CC</sub> × 0.3 | V  |  |
|                                      |                 |   |                          | 2.0                 | 1.9                   | 2.0  | _                     | 1.9                   | _                     |    |  |
| I Bala Javal autout                  |                 |   | I <sub>OH</sub> = -50 μA | 3.0                 | 2.9                   | 3.0  | _                     | 2.9                   | _                     | V  |  |
| High-level output voltage            | Vон             | VIN = VIH or VIL  |                          | 4.5                 | 4.4                   | 4.5  | _                     | 4.4                   | _                     |    |  |
| 95                                   |                 |   | $I_{OH} = -4 \text{ mA}$ | 3.0                 | 2.58                  | _    | _                     | 2.48                  | _                     |    |  |
|                                      |                 |   | $I_{OH} = -8 \text{ mA}$ | 4.5                 | 3.94                  | _    | _                     | 3.80                  | _                     |    |  |
|                                      | VoL             | V <sub>IN</sub><br>= V <sub>IH</sub> or V <sub>IL</sub> | I <sub>OL</sub> = 50 μA  | 2.0                 | _                     | 0.0  | 0.1                   | _                     | 0.1                   | V  |  |
|                                      |                 |   |                          | 3.0                 | _                     | 0.0  | 0.1                   | _                     | 0.1                   |    |  |
| Low-level output voltage             |                 |   |                          | 4.5                 | _                     | 0.0  | 0.1                   | _                     | 0.1                   |    |  |
| voltago                              |                 |   | I <sub>OL</sub> = 4 mA   | 3.0                 |                       |      | 0.36                  | _                     | 0.44                  |    |  |
|                                      |                 |   | $I_{OL}$ = 8 mA          | 4.5                 | _                     | _    | 0.36                  | _                     | 0.44                  |    |  |
| 3-state output off-<br>state current | loz             | VIN = VIH or VIL<br>VOUT = VCC or GND                   |                          | 5.5                 |                       | _    | ±0.25                 | _                     | ±2.50                 | μΑ |  |
| Input leakage<br>current             | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND                          |                          | 0 to 5.5            | _                     | 1    | ±0.1                  | _                     | ±1.0                  | μА |  |
| Quiescent supply current             | Icc             | V <sub>IN</sub> = V <sub>CC</sub> or                    | GND                      | 5.5                 | _                     | _    | 4.0                   | _                     | 40.0                  | μΑ |  |

## Timing Requirements (input: tr = tf = 3 ns)

| Characteristics          | Symbol             | Test Condition | Ta = 25°C                      |        | Ta =<br>-40 to<br>85°C | Unit       |    |
|--------------------------|--------------------|----------------|--------------------------------|--------|------------------------|------------|----|
|                          |                    |                | V <sub>CC</sub> (V)            | Тур.   | Limit                  | Limit      |    |
| Minimum pulse width (LE) | t <sub>w (H)</sub> | _              | $3.3 \pm 0.3$<br>$5.0 \pm 0.5$ | _      | 5.0<br>5.0             | 5.0<br>5.0 | ns |
| Minimum set-up time      | ts                 | _              | $3.3 \pm 0.3$<br>$5.0 \pm 0.5$ | _      | 4.0<br>4.0             | 4.0<br>4.0 | ns |
| Minimum hold time        | th                 | _              | $3.3 \pm 0.3$<br>$5.0 \pm 0.5$ | _<br>_ | 1.0<br>1.0             | 1.0<br>1.0 | ns |



#### AC Electrical Characteristics (input: tr = tf = 3 ns)

| Characteristics               | Symbol           | Test Condition        |                                |                     | Ta = 25°C |      |      | Ta =<br>-40 to 85°C |      | Unit     |
|-------------------------------|------------------|-----------------------|--------------------------------|---------------------|-----------|------|------|---------------------|------|----------|
|                               | Cy               |                       | V <sub>CC</sub> (V)            | C <sub>L</sub> (pF) | Min       | Тур. | Max  | Min                 | Max  | <b>5</b> |
|                               |                  |                       | 3.3 ± 0.3                      | 15                  | _         | 7.0  | 11.0 | 1.0                 | 13.0 |          |
| Propagation delay time        | tpLH             |                       | 3.3 ± 0.3                      | 50                  | _         | 9.5  | 14.5 | 1.0                 | 16.5 |          |
| (LE-Q)                        | tpHL             | _                     | 5.0 ± 0.5                      | 15                  | _         | 4.9  | 7.2  | 1.0                 | 8.5  | ns       |
|                               |                  |                       | 5.0 ± 0.5                      | 50                  | _         | 6.4  | 9.2  | 1.0                 | 10.5 |          |
|                               |                  |                       | 3.3 ± 0.3                      | 15                  | 1         | 7.3  | 11.4 | 1.0                 | 13.5 |          |
| Propagation delay time        | tpLH             |                       | 3.3 ± 0.3                      | 50                  | _         | 9.8  | 14.9 | 1.0                 | 17.0 | ns       |
| (D-Q)                         | tpHL             | _                     | 5.0 ± 0.5                      | 15                  | _         | 5.0  | 7.2  | 1.0                 | 8.5  | 115      |
|                               |                  |                       |                                | 50                  | _         | 6.5  | 9.2  | 1.0                 | 10.5 |          |
|                               | tpZL<br>tpZH     | R <sub>L</sub> = 1 kΩ | 3.3 ± 0.3                      | 15                  | _         | 7.3  | 11.4 | 1.0                 | 13.5 | ns       |
| 3-state output enable         |                  |                       |                                | 50                  | _         | 9.8  | 14.9 | 1.0                 | 17.0 |          |
| time                          |                  |                       | 5.0 ± 0.5                      | 15                  | _         | 5.5  | 8.1  | 1.0                 | 9.5  |          |
|                               |                  |                       |                                | 50                  | _         | 7.0  | 10.1 | 1.0                 | 11.5 |          |
| 3-state output disable        | t <sub>pLZ</sub> | R <sub>I</sub> = 1 kΩ | $3.3 \pm 0.3$                  | 50                  | _         | 9.5  | 13.2 | 1.0                 | 15.0 | ns       |
| time                          | $t_{pHZ}$        | KL - 1 K22            | $5.0 \pm 0.5$                  | 50                  | _         | 6.5  | 9.2  | 1.0                 | 10.5 | 115      |
| Output to output akow         | tosLH            | (Note 1)              | $3.3 \pm 0.3$<br>$5.0 \pm 0.5$ | 50                  | _         | _    | 1.5  | _                   | 1.5  | ns       |
| Output to output skew         | tosHL            | (Note 1)              |                                | 50                  | _         | _    | 1.0  | _                   | 1.0  | 115      |
| Input capacitance             | C <sub>IN</sub>  |                       | _                              |                     | _         | 4    | 10   | _                   | 10   | pF       |
| Output capacitance            | Cout             |                       |                                |                     | -         | 6    | _    | _                   | _    | pF       |
| Power dissipation capacitance | C <sub>PD</sub>  |                       |                                | (Note 2)            | _         | 27   | _    | _                   | _    | pF       |

Note 1: Parameter guaranteed by design.

tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|

Note 2: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per latch)

And the total CPD when n pcs. of Latch operate can be gained by the following equation:

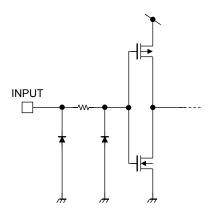
CPD (total) = 14 + 13·n



## Noise Characteristics (input: tr = tf = 3 ns)

| Characteristics                              | Cumbal           | Test Condition         | Ta =                | Unit |      |       |
|--|------------------|------------------------|---------------------|------|------|-------|
| Characteristics                              | Symbol           |                        | V <sub>CC</sub> (V) | Тур. | Max  | Offic |
| Quiet output maximum dynamic V <sub>OL</sub> | VOLP             | C <sub>L</sub> = 50 pF | 5.0                 | 0.5  | 8.0  | V     |
| Quiet output minimum dynamic V <sub>OL</sub> | Volv             | C <sub>L</sub> = 50 pF | 5.0                 | -0.5 | -0.8 | V     |
| Minimum high level dynamic input voltage     | V <sub>IHD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 3.5  | V     |
| Maximum low level dynamic input voltage      | V <sub>ILD</sub> | C <sub>L</sub> = 50 pF | 5.0                 | _    | 1.5  | V     |

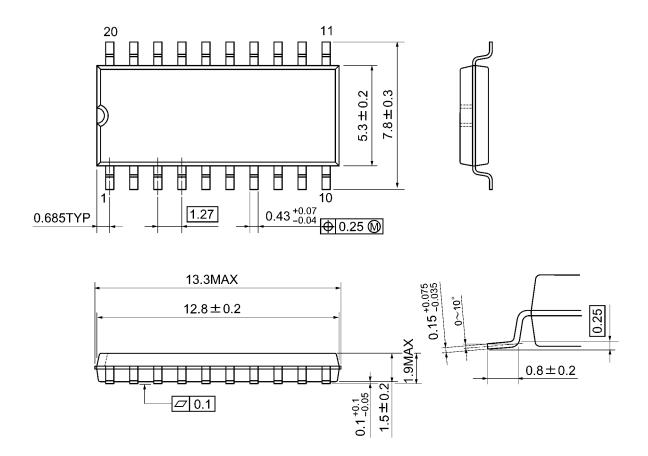
## **Input Equivalent Circuit**





## **Package Dimensions**

SOP20-P-300-1.27A Unit: mm

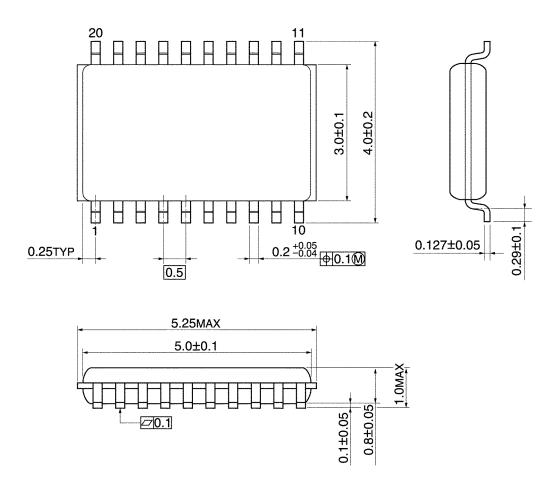


Weight: 0.22 g (typ.)



## **Package Dimensions**

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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